

AN APPROACH FOR CIRCUIT DESIGN OPTMIZATION BASED ON COMPLEXITY CONSIDERATIONS

Abstract

Optimizing circuit trade-offs is a highly challenging task for any design team. This challenge is further exacerbated with the additional design complexity of integrating multiple circuits. Today, with the increasing demand for newer wireless communication products, design teams face a shorter time-to-market (TTM) for every generation of their new products and each product requires major improvement in wireless capability. Hence, it is important for the design teams to design circuits with complexity in mind. A design methodology divided into architecture complexity, component complexity and discrecional complexity are proposed. A novel benchmarking figure-of-merit, complexity factor (CF), was formulated and proposed for the architecture complexity. A simulated application of a goal, gain optimization, demonstrated and revealed that a reduction of up to 400% in the normalized complexity factor (NCF) could enhance the gain performance by approximately up to 40% for ultra-high frequency (UHF) applications. As the number of variables to be permuted is very high for the power amplifier (PA) blocks from circuit down to the process level, it is treated as a black box in the analysis but the next topology complexity step addressed this. Two topologies were proposed; a cascode 2-stacked EDNFET and SGNFET and a cascode 4-stacked resistor-ladder SGNFET PA. Both of

them achieved a near 20dBm output power and approximately 60% efficiency on the test-chips measurements, which demonstrated that the 2-stacked EDNFET and SGNFET topology with a reduction in stack height is a potential candidate for a reduced difficulty and complexity DPA design. In the discretional complexity step, we proposed a broadside coupler designed on 65nm CMOS process delivering a S21 and S31 of almost -4dB designed with 0.4dB of over-coupling. The spread of the phase difference is less than 2.2° from 57GHz to 66GHz, which is only a 2.4% margin deviation. The broadside coupler has a reduced complexity compared with a Wilkinson power divider with a broader bandwidth and we implemented this into a DPA with a gm3 cancellation bias scheme tapping on its intrinsic linearization property, without adding external circuitry to increase the complexity of the overall circuit but at the same time, improve its linearity by 6-8dB compared to a DPA optimized for power and more than 10dB compared with a balance PA with a similar structure.

Publications

Aaron Tan, Rui Tze Toh, Yongfu Li, Alfred Lim, Zhi Hui Kong, Kaixue Ma, Kiat Seng Yeo, “A Methodology To Evaluate Circuit Complexity: Doherty Power Amplifier As A Case Study” *Submitted*

Rui Tze Toh, Shyam Parthasarathy, Aaron Tan, Amit Kumar Sahoo, Jen Shuang Wong, Shaoqiang Zhang, Madabusi Govindarajan, Kok Wai Chew, “Power Amplifier Topologies Using EDNMOS On CMOS-SOI For Sub-6 GHz Wireless Applications” *Pending Submission*

Aaron Tan, Kaixue Ma, Kiat Seng Yeo, Zhi Hui Kong, “A Compact 60GHz CMOS Doherty Power Amplifier,” *published in IEEE Asia Pacific Wireless Communication Symposium (APWCS)*, 2015

A. Tan, K. Ma, Z. H. Kong, and K. S. Yeo, "A Gm3 cancellation bias for 60GHz Doherty Power Amplifier," in *2015 International SoC Design Conference (ISOCC)*, 2015, pp. 195-196.

Alfred Lim, Aaron Tan, Zhi Hui Kong, Kaixue Ma, Kiat Seng Yeo, “A 2.4-Ghz Transformer-Based Class-E Power Amplifier” *Submitted*